

Thyristor \ Diode Module

= 2x 2200 V

104 A

 V_{τ} 1.46 V

Phase leg

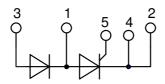
Part number

MCD94-22io1B



Backside: isolated

F1 E72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- · Reduced weight
- Advanced power cycling

Terms _Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747 and per semiconductor unless otherwise specified

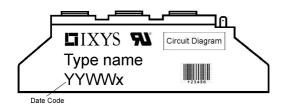
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Rectifier		O a salini a			Ratings		
Symbol	Definition	Conditions	T 0500	min.	typ.	max.	Un
V _{RSM/DSM}	max. non-repetitive reverse/forwa		$T_{VJ} = 25^{\circ}C$			2100	'
V _{RRM/DRM}	max. repetitive reverse/forward bloom		$T_{VJ} = 25^{\circ}C$			2200	'
I _{R/D}	reverse current, drain current	$V_{R/D} = 2200 \text{ V}$	$T_{VJ} = 25^{\circ}C$			200	μ
		$V_{R/D} = 2200 \text{ V}$	$T_{VJ} = 125^{\circ}C$			15	m
V _T	forward voltage drop	$I_T = 150 A$	$T_{VJ} = 25^{\circ}C$			1.44	١
		$I_{T} = 300 \text{ A}$				1.74	'
		$I_T = 150 A$	$T_{VJ} = 125$ °C			1.46	,
		$I_{T} = 300 \text{ A}$				1.99	! !
ITAV	average forward current	$T_C = 85^{\circ}C$	$T_{VJ} = 125$ °C			104	,
I _{T(RMS)}	RMS forward current	180° sine				163	
V _{T0}	threshold voltage	and the state of t	T _{vJ} = 125°C			0.85	١
r _T	slope resistance	ess calculation only				3.2	m۵
R _{thJC}	thermal resistance junction to cas	e				0.22	K/V
R _{thCH}	thermal resistance case to heatsing	nk			0.20		K/V
P _{tot}	total power dissipation		T _C = 25°C			455	٧
I _{TSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{v.i} = 45^{\circ}C$			1.70	k/
10111		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.84	k/
		t = 10 ms; (50 Hz), sine	T _{v.i} = 125°C			1.45	k/
		t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			1.56	k
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			14.5	<u> </u>
	Table 12 120 iig	t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			14.0	1
		t = 0.0 ms; (50 Hz), sine	T _{vJ} = 125°C			10.4	İ
		t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			10.1	kA ²
C _J	junction capacitance	$V_{R} = 700 \text{ V} f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		63	10.1	pl
P _{GM}		$t_{\rm P} = 30 \mu {\rm s}$	$T_{\rm VJ} = 25 \rm G$ $T_{\rm C} = 125 \rm ^{\circ}C$		00	10	V
□ GM	max. gate power dissipation	·	1 _C = 123 O			5	۷
n		t _P = 300 μs				_	l
P _{GAV}	average gate power dissipation	T 40500 (5011	1'1' L 050 A			0.5	V
(di/dt) _{cr}	critical rate of rise of current	$T_{VJ} = 125 ^{\circ}\text{C}; f = 50 \text{Hz}$	•			150	A/μ
	$t_p = 200 \mu s; di_g/dt = 0.45 A/\mu s;$						• /
			on-repet., $I_T = 104 A$			500	<u> </u>
(dv/dt) _{cr}	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125$ °C			1000	V/µ
		R _{GK} = ∞; method 1 (linear volta					! ! !
V_{GT}	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			1.5	١
			$T_{VJ} = -40$ °C			1.6	١
I _{GT}	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			150	m/
			$T_{VJ} = -40$ °C			200	m/
V _{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^{\circ}C$			0.25	١
I _{GD}	gate non-trigger current					10	m/
I _L	latching current	t _p = 10 μs	$T_{VJ} = 25$ °C			200	m/
		$I_G = 0.45 \text{A}; di_G/dt = 0.45 \text{A/}\mu s$	3				
I _H	holding current	V _D = 6 V R _{GK} = ∞	$T_{VJ} = 25^{\circ}C$			150	m
t _{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	T _{VJ} = 25°C			2	μ
gu	-	$I_G = 0.45 \text{A}; di_G/dt = 0.45 \text{A}/\mu s$	-			_	
t _q	turn-off time	$V_{\rm R} = 100 \text{ V}; \ I_{\rm T} = 150 \text{ A}; \ V = \frac{2}{3}$			185		μ
• q		-H = 100 v, IT = 100/1, v = /	DKW 1 A7 - 100 Q		.00		μ



Package	Package TO-240AA				Ratings			
Symbol	Definition	Conditions			min.	typ.	max.	Unit
RMS	RMS current	per terminal					200	Α
T _{vJ}	virtual junction temperature				-40		125	°C
Top	operation temperature				-40		100	°C
T _{stg}	storage temperature				-40		125	°C
Weight						81		g
M _D	mounting torque				2.5		4	Nm
$\mathbf{M}_{_{T}}$	terminal torque				2.5		4	Nm
d _{Spp/App}	creepage distance on surface striking dista	striking distance through air	terminal to terminal	13.0	9.7			mm
$d_{\text{Spb/Apb}}$	creepage distance on surface	Striking distance through an	terminal to backside	16.0	16.0			mm
V _{ISOL}	isolation voltage	t = 1 second	50/00 II 5140 I		3600		٧	
.002	t = 1 minute		50/60 Hz, RMS; IISOL ≤ 1 mA		3000			٧

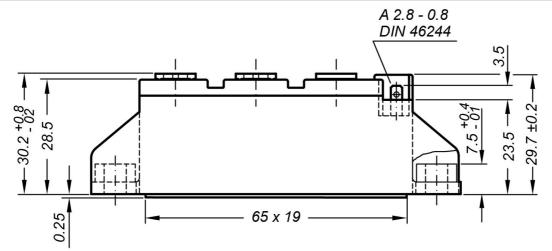


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCD94-22io1B	MCD94-22io1B	Box	36	470244

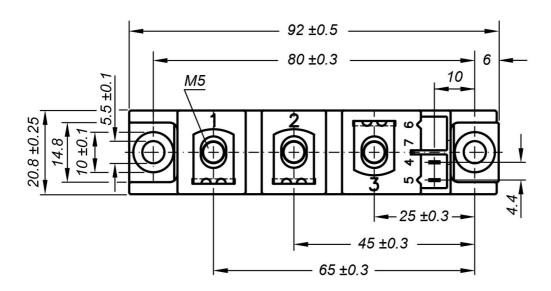
Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 125 ^{\circ}\text{C}$
$I \rightarrow V_0$	R_0	Thyristor		
V _{0 max}	threshold voltage	0.85		V
$R_{0 \; \text{max}}$	slope resistance *	2		$m\Omega$



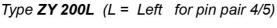
Outlines TO-240AA

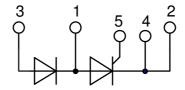


General tolerance: DIN ISO 2768 class "c"



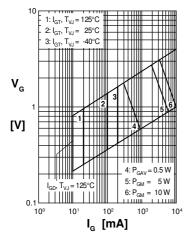
Optional accessories: Keyed gate/cathode twin plugs Wire length: 350 mm, gate = white, cathode = red UL 758, style 3751

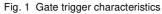






Thyristor





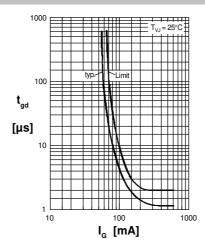


Fig. 2 Gate trigger delay time